



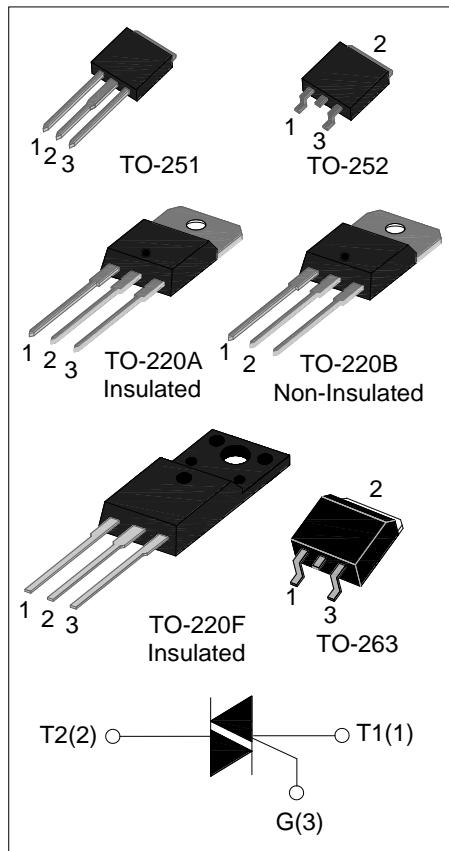
## T0610H/T0620H/T0635H/T0650H Series 6A TRIACs

Rev.3.0

## DESCRIPTION:

T06xxH series triacs of high junction temperature with high dv/dt rate with strong resistance to electromagnetic interference provide high ability to withstand the shock loading of large current. They are especially recommended for use on inductive load and high environment temperature condition.

T06xxH-xxA provides insulation voltage rated at 2500V RMS and T06xxH-xxF provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink complying with UL standards (File ref: E252906).



## MAIN FEATURES

Symbol	Value	Unit
$I_T(\text{RMS})$	6	A
$V_{\text{DRM}} / V_{\text{RRM}}$	600 and 800	V
$T_{j\max}$	150	°C

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{\text{stg}}$	-40-150	°C
Operating junction temperature range	$T_j$	-40-150	°C
Repetitive peak off-state voltage( $T_j=25^\circ\text{C}$ )	$V_{\text{DRM}}$	600/800	V
Repetitive peak reverse voltage( $T_j=25^\circ\text{C}$ )	$V_{\text{RRM}}$	600/800	V
Non repetitive surge peak Off-state voltage	$V_{\text{DSM}}$	$V_{\text{DRM}} + 100$	V
Non repetitive peak reverse voltage	$V_{\text{RSM}}$	$V_{\text{RRM}} + 100$	V
RMS on-state current	$I_{T(\text{RMS})}$	6	A
TO-251/ TO-252( $T_c=86^\circ\text{C}$ )			
TO-220A(Ins)/ TO-220F(Ins) ( $T_c=96^\circ\text{C}$ )			
TO-220B(Non-Ins)( $T_c=107^\circ\text{C}$ )			
TO-263 ( $T_c=113^\circ\text{C}$ )			

Non repetitive surge peak on-state current (full cycle, F=50Hz)	I <sub>TSM</sub>	60	A
I <sup>2</sup> t value for fusing (tp=10ms)	I <sup>2</sup> t	21	A <sup>2</sup> s
Critical rate of rise of on-state current (I <sub>G</sub> =2×I <sub>GT</sub> )	dI/dt	50	A/μs
Peak gate current	I <sub>GM</sub>	2	A
Average gate power dissipation	P <sub>G(AV)</sub>	1	W
Peak gate power	P <sub>GM</sub>	5	W

ELECTRICAL CHARACTERISTICS (T<sub>j</sub>=25°C unless otherwise specified)

Symbol	Test Condition	Quadrant		Value				Unit
				T0610H	T0620H	T0635H	T0650H	
I <sub>GT</sub>	V <sub>D</sub> =12V R <sub>L</sub> =33Ω	I - II -III	MAX	10	20	35	50	mA
V <sub>GT</sub>		I - II -III	MAX	1.5				V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =150°C R <sub>L</sub> =3.3KΩ	I - II -III	MIN	0.2				V
I <sub>L</sub>	I <sub>G</sub> =1.2I <sub>GT</sub>	I -III	MAX	15	40	50	70	mA
		II		25	55	70	100	
I <sub>H</sub>	I <sub>T</sub> =100mA		MAX	15	30	45	60	mA
dV/dt	V <sub>D</sub> =2/3V <sub>DRM</sub> R <sub>GK</sub> =1KΩ T <sub>j</sub> =150°C		MIN	200	500	1000	1500	V/μs
(dV/dt)c	V <sub>D</sub> =400V T <sub>j</sub> =150°C (dI/dt)c=-2.6A/ms		MIN	2	5	15	20	V/μs

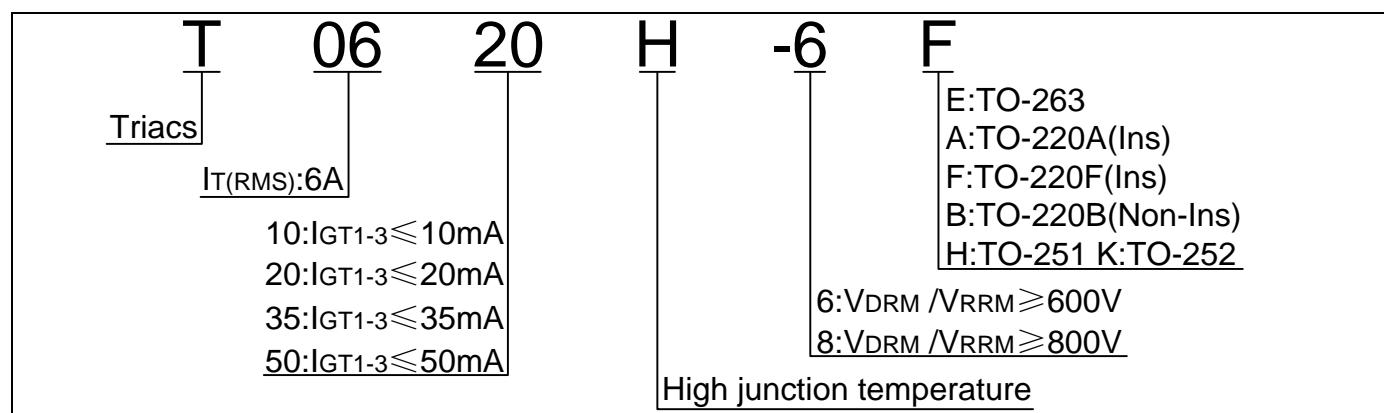
## STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
V <sub>TM</sub>	I <sub>TM</sub> =8.5A tp=380μs	T <sub>j</sub> =25°C	1.55	V
I <sub>DRM</sub>		T <sub>j</sub> =25°C	5	μA
I <sub>RRM</sub>	V <sub>D</sub> =V <sub>DRM</sub> V <sub>R</sub> =V <sub>RRM</sub>	T <sub>j</sub> =150°C	1.5	mA

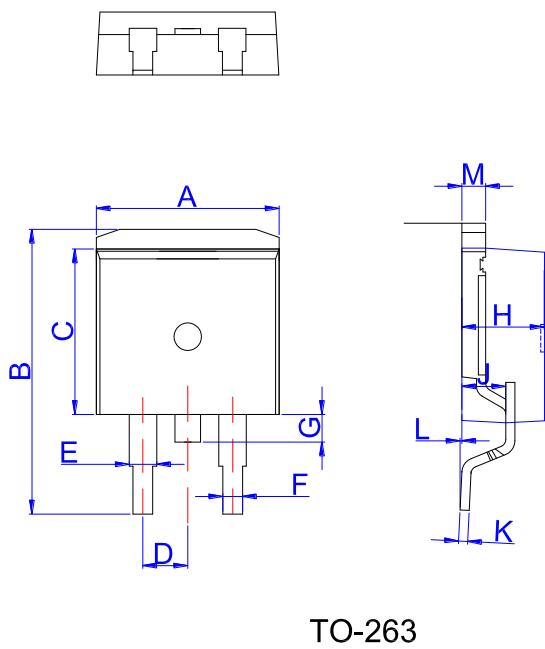
## **THERMAL RESISTANCES**

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-251/TO-252	4.2
		TO-220A(Ins)/ TO-220F(Ins)	3.9
		TO-220B(Non-Ins)	2.7
		TO-263	2.1

## **ORDERING INFORMATION**

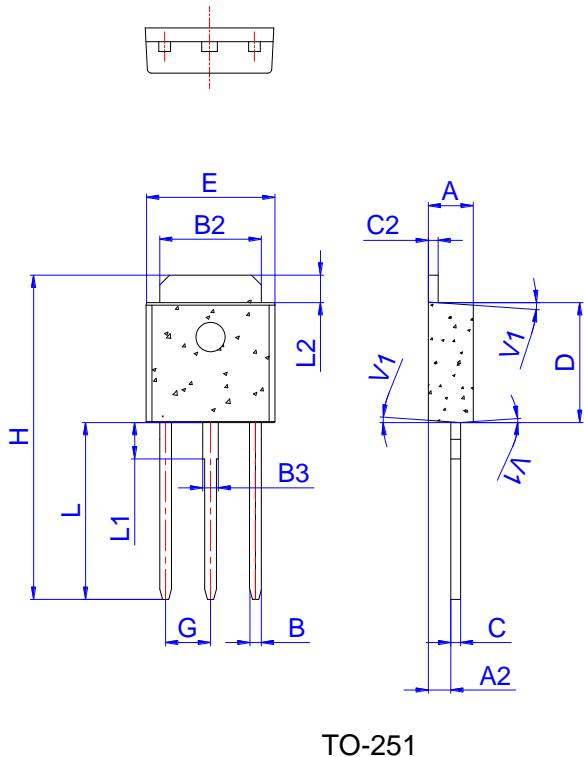


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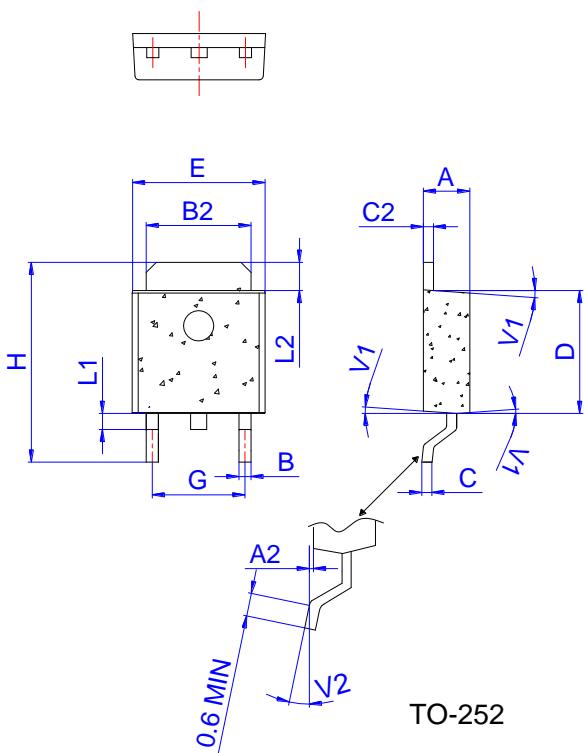


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.4		9.6	0.37		0.378
D		2.54			0.100	
E	1.20		1.40	0.047		0.055
F	0.75		0.85	0.029		0.033
G			1.75			0.069
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
M	1.25		1.35	0.049		0.053

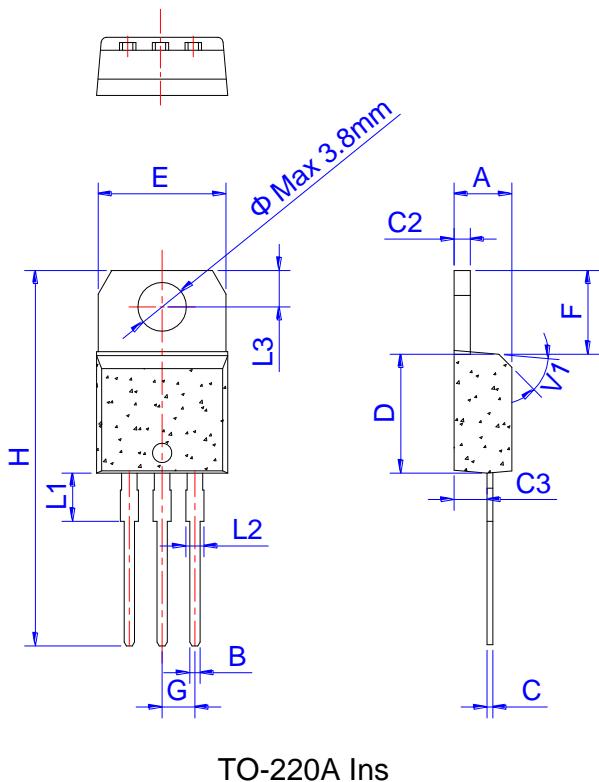
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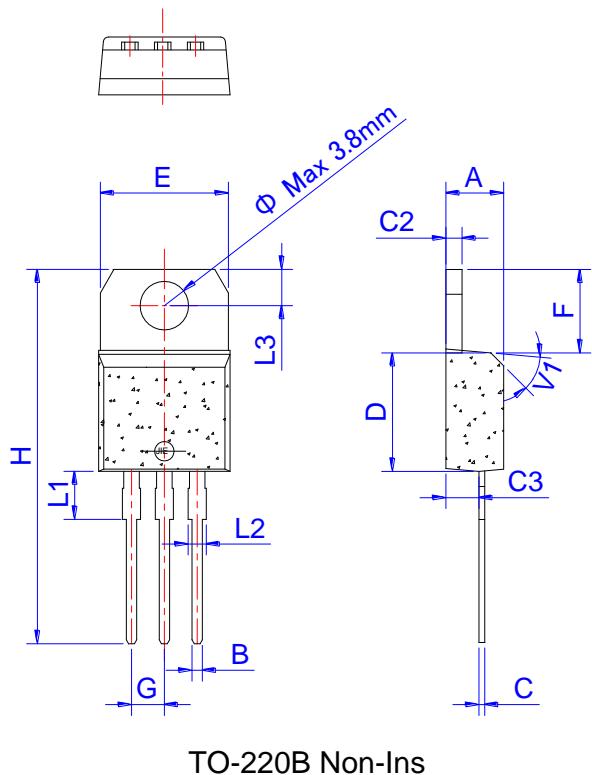
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.095
A2	0.90		1.20	0.035		0.047
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
B3	0.76		0.85	0.030		0.033
C	0.45		0.62	0.018		0.024
C2	0.48		0.62	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.70	0.252		0.264
G		2.30			0.091	
H	16.0		17.0	0.630		0.669
L	8.90		9.40	0.350		0.370
L1	1.80		1.90	0.071		0.075
L2	1.37		1.50	0.054		0.059
V1		4°			4°	



## PACKAGE MECHANICAL DATA

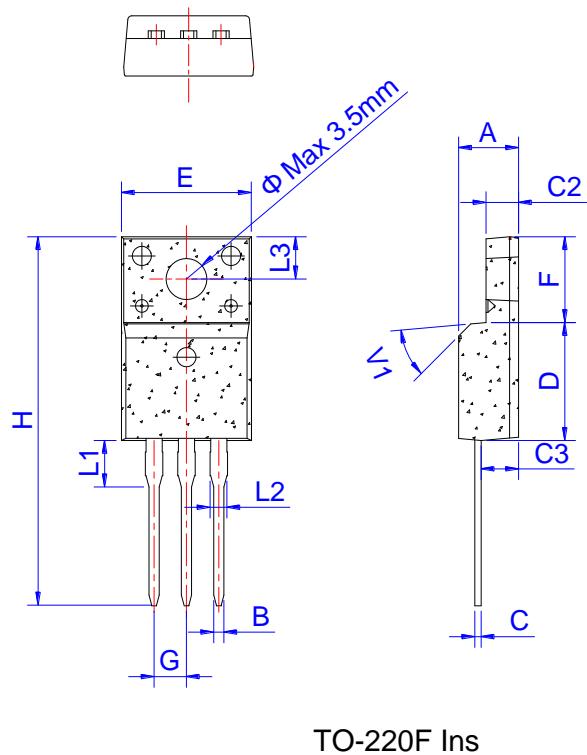


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	



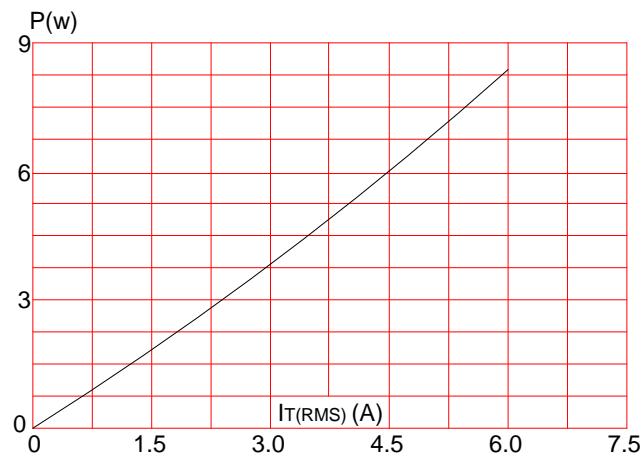
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.60		10.4	0.378		0.409
F	6.20		6.60	0.244		0.260
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

## PACKAGE MECHANICAL DATA

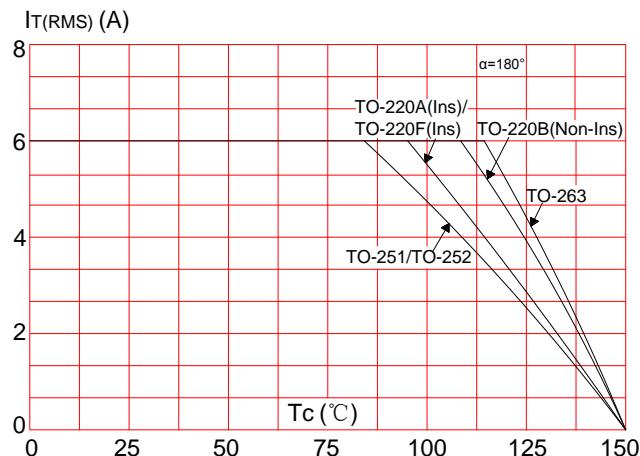


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.80	0.173		0.189
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.48		0.75	0.019		0.030
C2	2.40		2.70	0.094		0.106
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.70		10.3	0.382		0.406
F	6.40		7.00	0.252		0.276
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.63			0.143	
L2	1.14		1.70	0.045		0.067
L3		3.30			0.130	
V1		45°			45°	

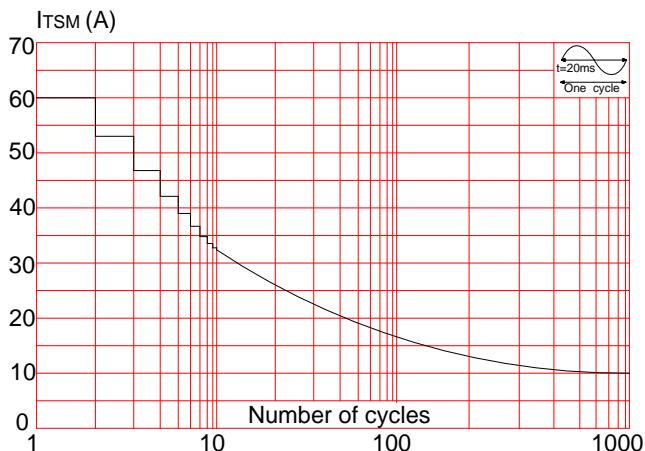
**FIG.1** Maximum power dissipation versus RMS on-state current



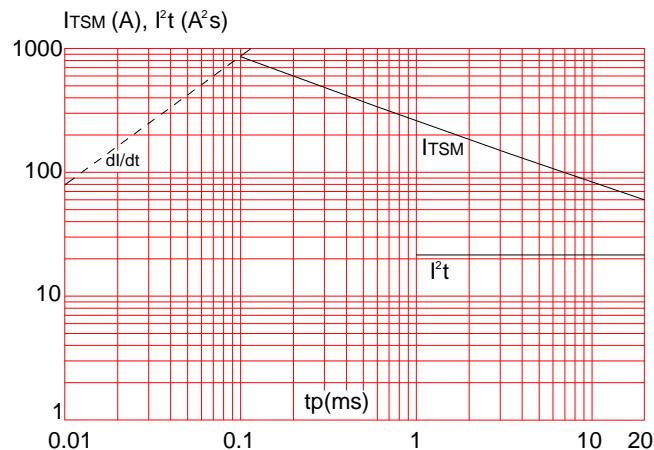
**FIG.2:** RMS on-state current versus case temperature



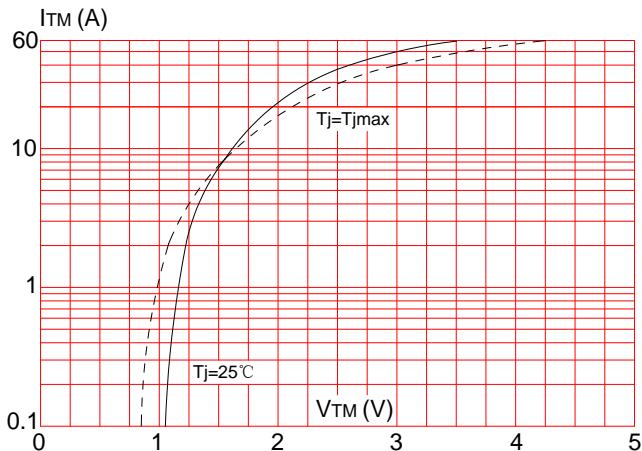
**FIG.3:** Surge peak on-state current versus number of cycles



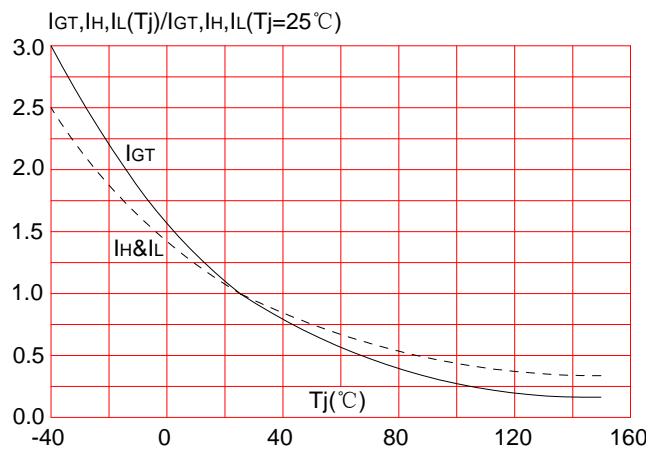
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 20\text{ms}$ , and corresponding value of  $I^2t$  ( $\text{dI}/\text{dt} < 50\text{A}/\mu\text{s}$ )



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature



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